



Nb3Sn and NbTiN progress towards Cavity coating

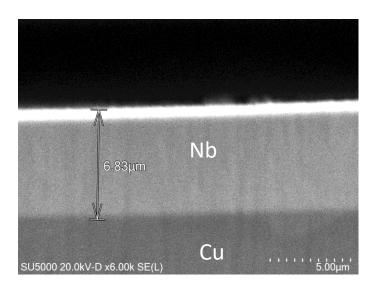
14th IFAST WP9 Quarterly Meeting

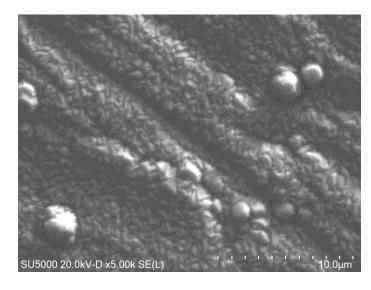


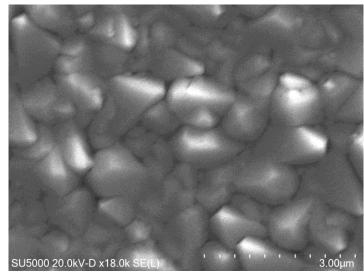


Nb3Sn Deposition Temperature Optimisation



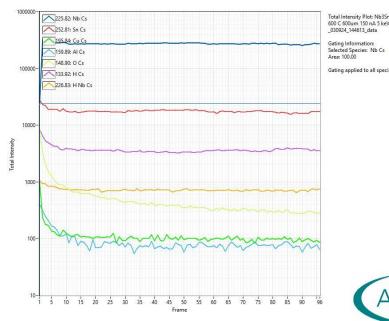






- Nb3Sn with bulk like properties is synthesised at 570 C and 50 W
- ➤ The film is very uniform in stoichiometry through out the depth with the lowest level of oxygen and Cu
- Very sharp interface and good adhesion

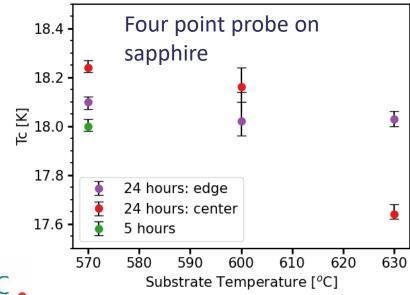




Total Intensity Plot: Nb3Sn, 23_24 0824 on Cu
500 C 600um 150 nA 5 keV.
300 C 600um 150 nA 5 keV.
3030224_144613_data

Sating Information:
Selected Species: Nb Cs
Area: 100,00

Sating applied to all species

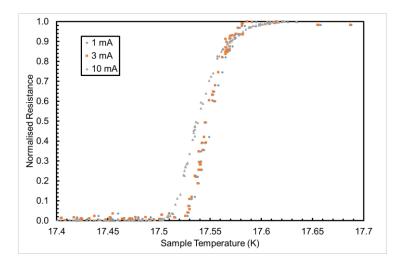


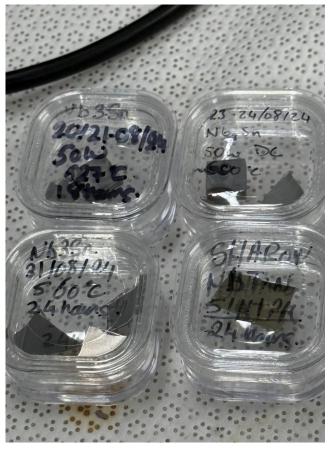






- Three of the samples with the highest Tc were sent for point contact tunnelling (PDC) for both TC, bandgap measurement and XRD.
- For each set both sapphire and copper witness sample was sent.
- Also a NbTiN deposited on sapphire in Sharon for 24 hours and RRR tested here which gave 17.was also sent.
- ➤ Nb3Sn and NbTiN also sent to HZBDR for positron annihilation for point defect measurement.



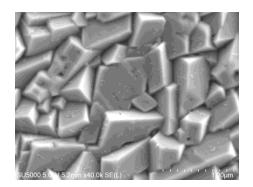


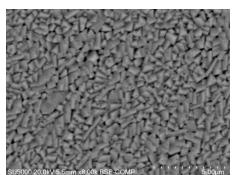


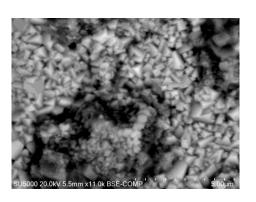


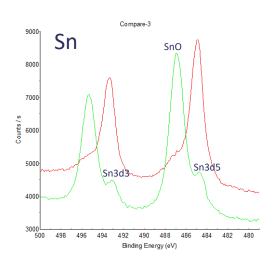
Nb3Sn dep on INFN Cu after NEG Cartridge

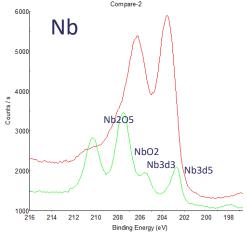


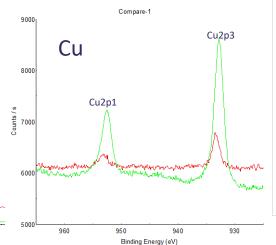


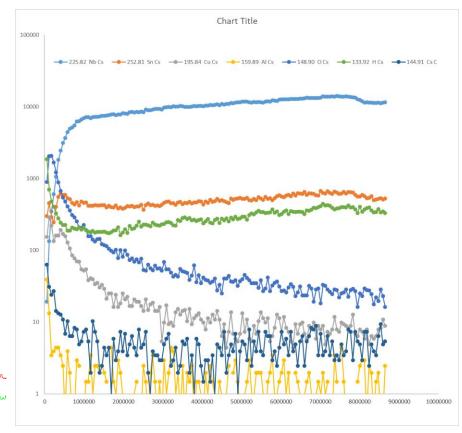










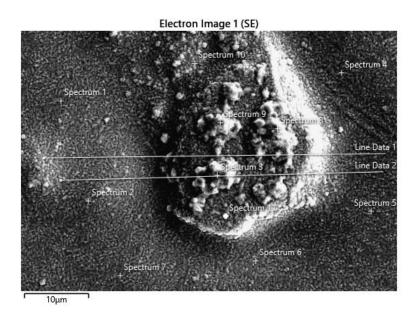


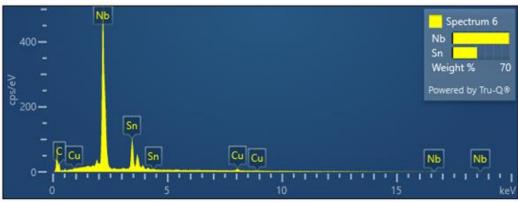




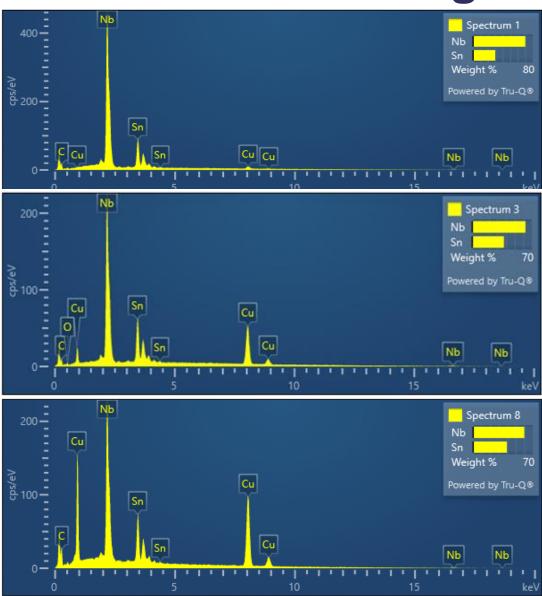
Nb3Sn dep on INFN Cu after NEG Cartridge











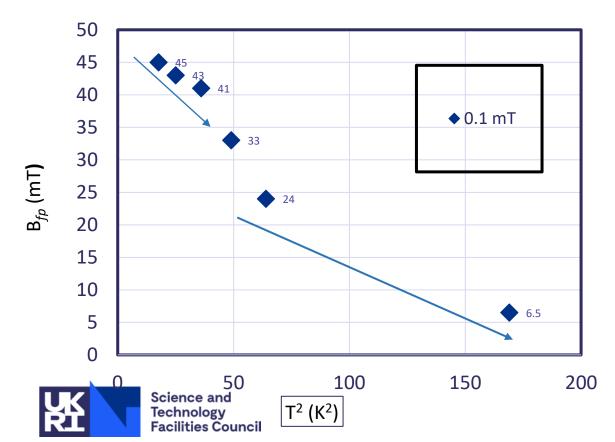


Nb3Sn 25/01/25

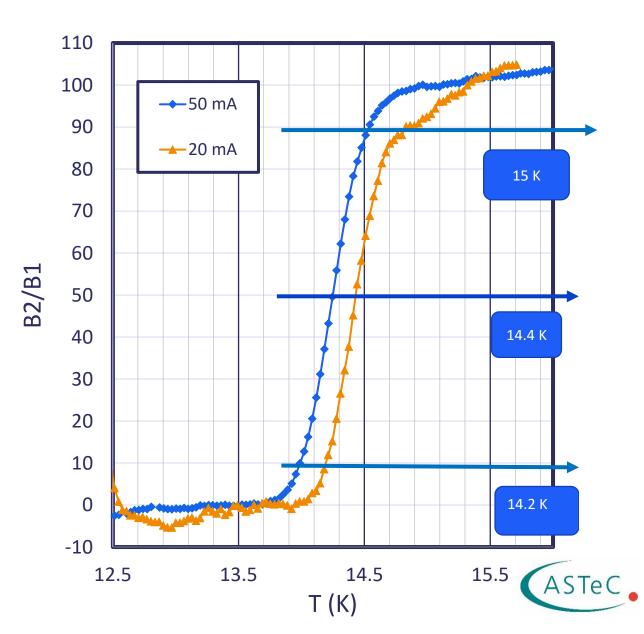


Sample deposited by INFN and tested at Daresbury Laboratory.

Point of full Flux Penetration $[B_{fp}]$ measured by the Magnetic Field Penetration Facility [MFPF].



Critical Temperature [T_c] measured by the Magnetic Field Penetration Facility [MFPF].





6 GHz cavity





6 GHz cavity deposited NbTiN













- Cavity to be shipped to INFN
- ➤ Ideally tested at low power at Daresbury and then sent to INFN.
- Waiting for new cavity to be shipped from INFN





NbTiN (Twisted)(Rod)

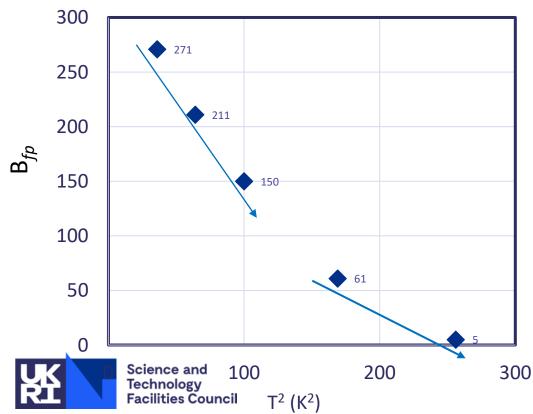
17/01/25. Darcy.

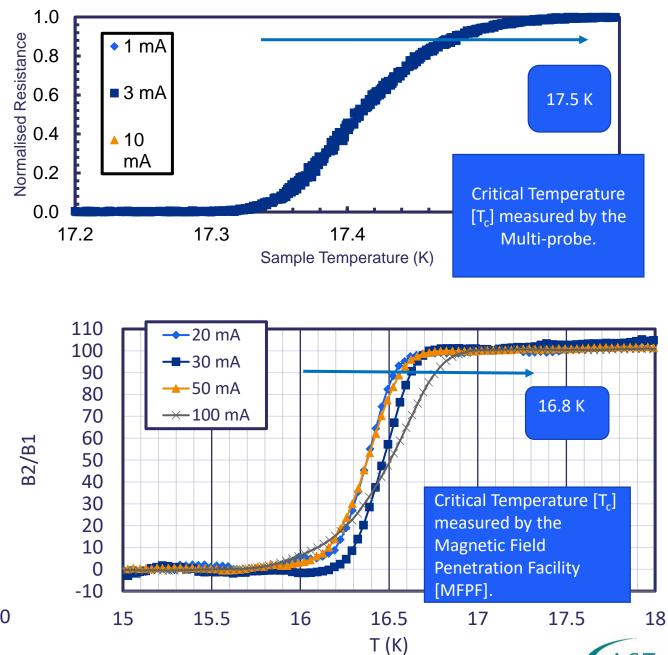


Two samples tested:

- \triangleright Multi-probe: T_c measured on Sapphire [\emptyset = < 10mm].
- \triangleright MFPF: $B_{fo} \& T_c$ measured on Cu [\emptyset = 50 mm].

Point of full Flux Penetration $[B_{fp}]$ measured by the Magnetic Field Penetration Facility [MFPF].





Future work

Planar samples:

- ❖ Nb3Sn on copper disk for RF surface resistance
 - Nb3Sn on Thick Nb underlayer
 - Nb3Sn with 3 different layer thickness 6h, 12h and 24 hours
 - V3Si on copper(Lower Priority)
- ❖ Nb3Sn on Sapphire disk
 - With copper under layer
 - With copper under layer and Nb
- > QPR
 - ❖ Waiting for the QPR to arrive from HZB
- 6 GHz Cavity
 - Close cavity with NbTiN deposition in Darcy (to be measured at INFN)
 - Open cavity with Nb3Sn deposition in Sharon new chamber (to be measured at Surf lab)
- > 1.3 GHz cavity for Nb3Sn deposition
 - Open cavity
 - Close Nb cavity (3 cavities)
 - Close diamond turned Cu cavity from CERN
 - Close hydroformed Cu cavity coated with Nb at CERN ready for deposition of Nb3Sn.

